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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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## DATA SHEET

# MOS FIELD EFFECT TRANSISTOR NP80N04EHE, NP80N04KHE NP80N04CHE, NP80N04DHE, NP80N04MHE, NP80N04NHE

## SWITCHING N-CHANNEL POWER MOS FET

#### DESCRIPTION

These products are N-channel MOS Field Effect Transistors designed for high current switching applications.

#### **ORDERING INFORMATION**

PART NUMBER	LEAD PLATING	PACKING	PACKAGE	
NP80N04EHE-E1-AY Note1, 2			TO-263 (MP-25ZJ) typ. 1.4 g	
NP80N04EHE-E2-AY Note1, 2				
NP80N04KHE-E1-AY Note1	Pure Sn (Tin)	Tape 800 p/reel		
NP80N04KHE-E2-AY Note1			TO-263 (MP-25ZK) typ. 1.5 g	
NP80N04CHE-S12-AZ Note1, 2	Sn-Ag-Cu		TO-220 (MP-25) typ. 1.9 g	
NP80N04DHE-S12-AY Note1, 2			TO-262 (MP-25 Fin Cut) typ. 1.8 g	
NP80N04MHE-S18-AY Note1	Pure Sn (Tin)	Tube 50 p/tube	TO-220 (MP-25K) typ. 1.9 g	
NP80N04NHE-S18-AY Note1			TO-262 (MP-25SK) typ. 1.8 g	

Notes 1. Pb-free (This product does not contain Pb in the external electrode.)

2. Not for new design

### FEATURES

- Channel temperature 175 degree rated
- Super low on-state resistance

 $R_{\text{DS(on)}}$  = 8.0 m $\Omega\,$  MAX. (VGs = 10 V, ID = 40 A)

Low input capacitance

Ciss = 2200 pF TYP.

Built-in gate protection diode









(TO-263)



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The mark <R> shows major revised points.

The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

## ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (VGs = 0 V)	VDSS	40	V
Gate to Source Voltage (VDs = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C) <sup>Note1</sup>	ID(DC)	±80	А
Drain Current (Pulse) Note2	D(pulse)	±280	А
Total Power Dissipation (T <sub>A</sub> = 25°C)	Ρτ	1.8	W
Total Power Dissipation (Tc = 25°C)	Ρτ	120	W
Channel Temperature	Tch	175	°C
Storage Temperature	Tstg	–55 to +175	°C
Single Avalanche Current Note3	las	52/31/13	А
Single Avalanche Energy Note3	Eas	2.7/96/169	mJ

Notes 1. Calculated constant current according to MAX. allowable channel temperature.

- **2.** PW  $\leq$  10  $\mu$ s, Duty cycle  $\leq$  1%
- 3. Starting T<sub>ch</sub> = 25°C, R<sub>G</sub> = 25  $\Omega$ , V<sub>GS</sub> = 20  $\rightarrow$  0 V (See Figure 4.)

## THERMAL RESISTANCE

Channel to Case Thermal Resistance	$R_{th(ch-C)}$	1.25	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	83.3	°C/W

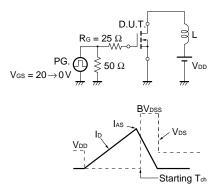
Characteristics	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Zero Gate Voltage Drain Current	Ibss	V <sub>DS</sub> = 40 V, V <sub>GS</sub> = 0 V			10	μA
Gate to Source Leakage Current	lgss	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V			±10	μA
Gate to Source Threshold Voltage	$V_{GS(th)}$	$V_{DS}$ = $V_{GS}$ , $I_D$ = 250 $\mu$ A	2.0	3.0	4.0	V
Forward Transfer Admittance	y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 40 A	15	31		S
Drain to Source On-state Resistance	RDS(on)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 40 A		6.2	8.0	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = 25 V,		2200	3300	pF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V,		490	730	pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		230	410	pF
Turn-on Delay Time	td(on)	V <sub>DD</sub> = 20 V, I <sub>D</sub> = 40 A,		24	52	ns
Rise Time	tr	V <sub>GS</sub> = 10 V,		14	36	ns
Turn-off Delay Time	td(off)	R <sub>G</sub> = 1 Ω		44	88	ns
Fall Time	tr			15	37	ns
Total Gate Charge	QG	V <sub>DD</sub> = 32 V,		40	60	nC
Gate to Source Charge	Q <sub>GS</sub>	V <sub>GS</sub> = 10 V,		12		nC
Gate to Drain Charge	Qgd	I <sub>D</sub> = 80 A		16		nC
Body Diode Forward Voltage	VF(S-D)	IF = 80 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 80 A, VGS = 0 V,		40		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>µ</i> s		50		nC

## ELECTRICAL CHARACTERISTICS (TA = 25°C)

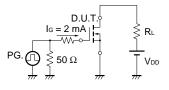
#### TEST CIRCUIT 1 AVALANCHE CAPABILITY

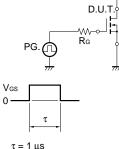
#### **TEST CIRCUIT 2 SWITCHING TIME**

+

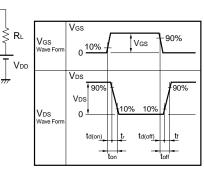


## TEST CIRCUIT 3 GATE CHARGE

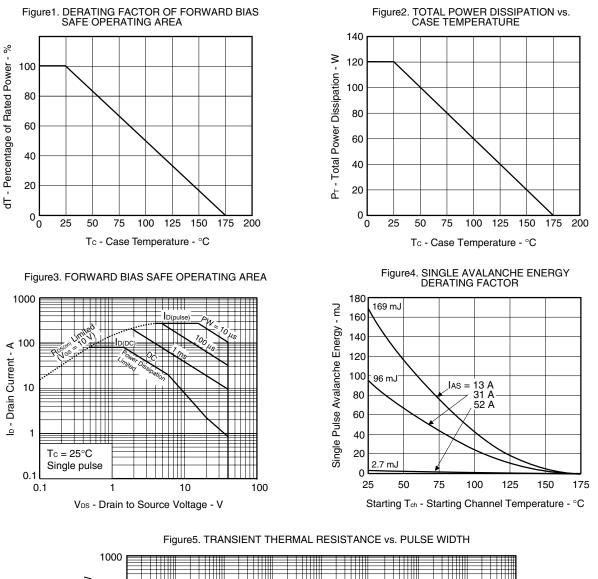


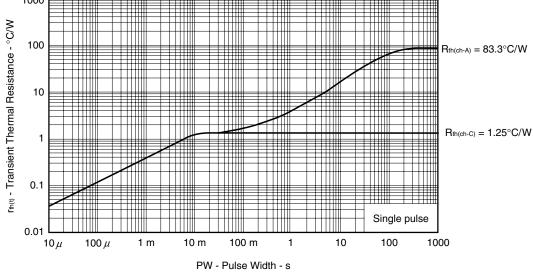


 $\begin{array}{l} \tau = 1 \; \mu s \\ \text{Duty Cycle} \leq 1\% \end{array}$ 



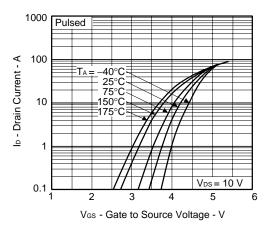
#### TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)



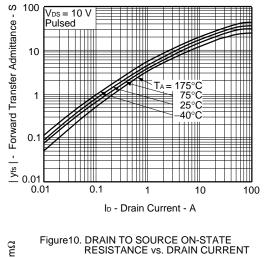


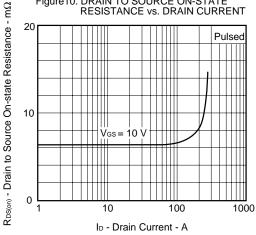
Data Sheet D14239EJ7V0DS

Figure6. FORWARD TRANSFER CHARACTERISTICS









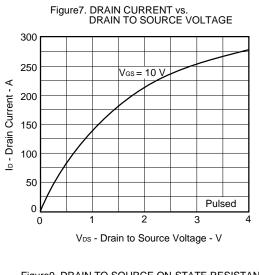
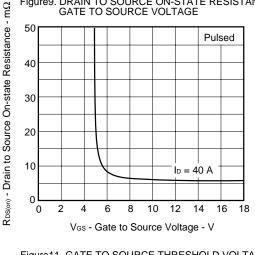
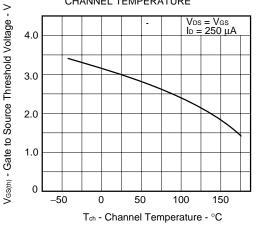


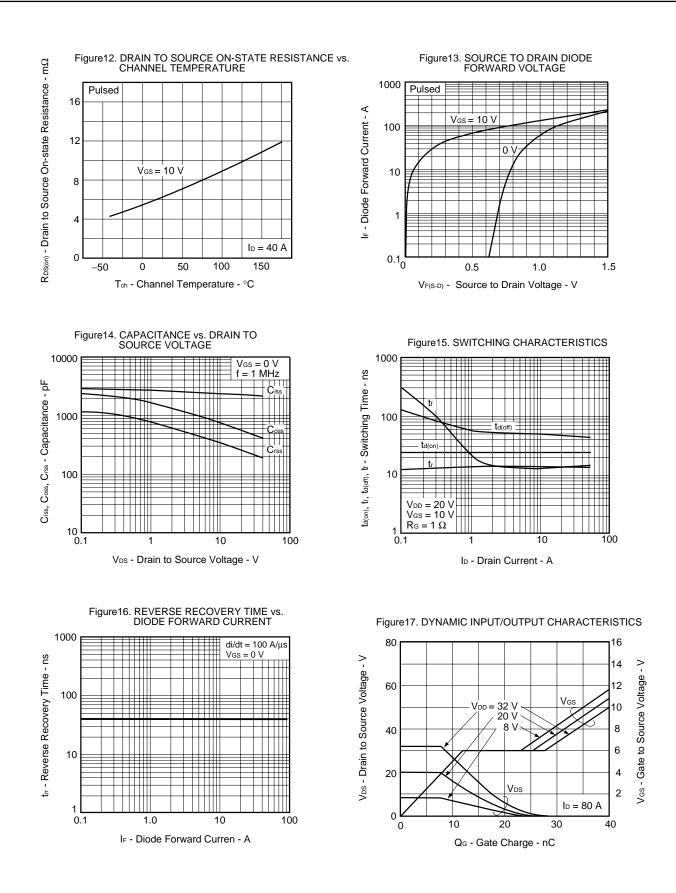
Figure9. DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE





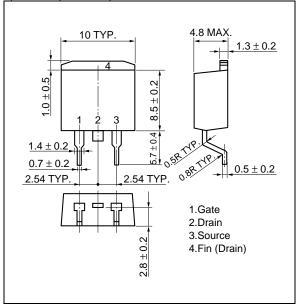


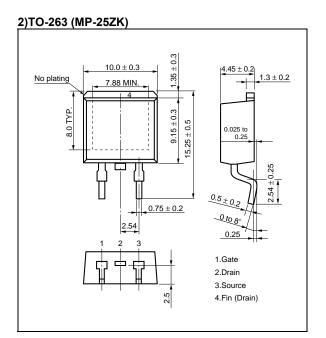
NEC



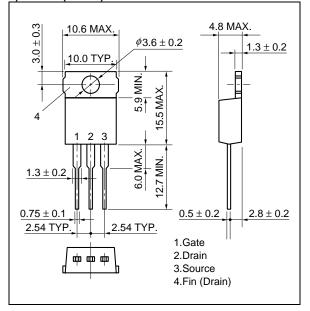
## PACKAGE DRAWINGS (Unit: mm)



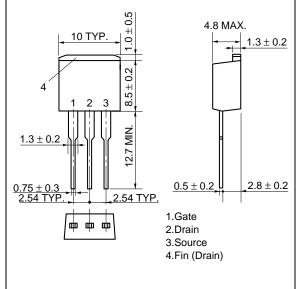




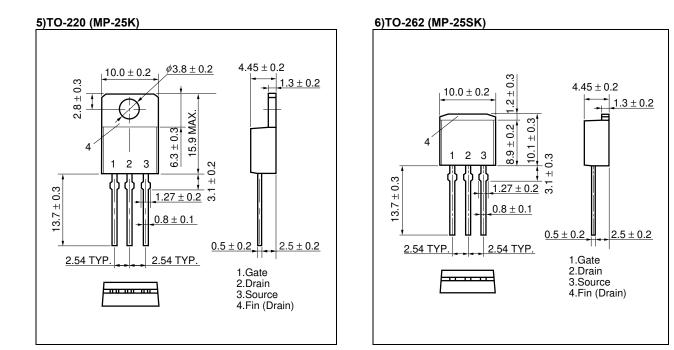
#### 3)TO-220 (MP-25) Note



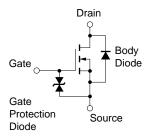
<R> 4)TO-262 (MP-25 Fin Cut) Note



Note Not for new design



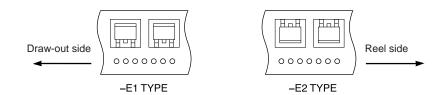
#### **EQUIVALENT CIRCUIT**



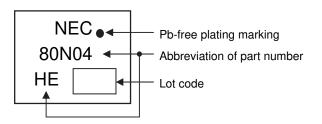
**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

## TAPE INFORMATION

There are two types (-E1, -E2) of taping depending on the direction of the device.



#### MARKING INFORMATION



### **RECOMMENDED SOLDERING CONDITIONS**

These products should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, please contact an NEC Electronics sales representative.

For technical information, see the following website.

Semiconductor Device Mount Manual (http://www.necel.com/pkg/en/mount/index.html)

Soldering Method	Soldering Conditions	Recommended Condition Symbol	
Infrared reflow	Maximum temperature (Package's surface temperature): 260°C or below		
MP-25ZJ, MP-25ZK	Time at maximum temperature: 10 seconds or less		
	Time of temperature higher than 220°C: 60 seconds or less	IR60-00-3	
	Preheating time at 160 to 180°C: 60 to 120 seconds		
	Maximum number of reflow processes: 3 times		
	Maximum chlorine content of rosin flux (percentage mass): 0.2% or less		
Wave soldering	Maximum temperature (Solder temperature): 260°C or below		
MP-25, MP-25K, MP-25SK,	Time: 10 seconds or less	THDWS	
MP-25 Fin Cut	Maximum chlorine content of rosin flux: 0.2% (wt.) or less		
Partial heating	Maximum temperature (Pin temperature): 350°C or below		
MP-25ZJ, MP-25ZK,	Time (per side of the device): 3 seconds or less	P350	
MP-25K, MP-25SK	Maximum chlorine content of rosin flux: 0.2% (wt.) or less		
Partial heating	Maximum temperature (Pin temperature): 300°C or below		
MP-25, MP-25 Fin Cut	Time (per side of the device): 3 seconds or less	P300	
	Maximum chlorine content of rosin flux: 0.2% (wt.) or less		

Caution Do not use different soldering methods together (except for partial heating).

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